







## **U310** N-Channel JFET

#### **Features**

- InterFET N0072L Geometry
- Low Noise: 2 nV/VHz Typical
- Low Ciss: 4pF Typical
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

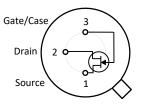
#### **Applications**

- Mixers
- Oscillators
- · VHF/UHF Amplifiers

#### Description

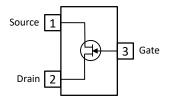
The -25V InterFET U310 JFET is targeted for higher gain VHF amplifiers, mixers, and oscillators. Gate leakages are typically less than 10pA at room temperatures.

#### **TO-52 Bottom View**



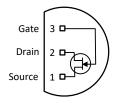


#### **SOT23 Top View**





#### **TO-92 Bottom View**





## **Product Summary**

	Parameters	U310 Min	Unit
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-25	V
I <sub>DSS</sub>	Drain to Source Saturation Current	24	mA
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-2.5	V
GFS	Forward Transconductance	10	mS

Ordering Information Custom Part and Rinning Ontions Available

Part Number	Description	Case	Packaging
U310	Through-Hole	TO-52	Bulk
PNU310	Through-Hole	TO-92	Bulk
SMPU310	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMPU310TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
U310COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
U310CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack



**Disclaimer:** It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.









## **Electrical Characteristics**

Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
$V_{RGS}$	Reverse Gate Source and Gate Drain Voltage	-25	V
I <sub>FG</sub>	Continuous Forward Gate Current	20	mA
PD	Continuous Device Power Dissipation	500	mW
Р	Power Derating	4	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 200	°C

Static Characteristics (@ TA = 25°C, Unless otherwise specified)

			U310			
	Parameters	Conditions	Min	Тур	Max	Unit
V <sub>(BR)GSS</sub>	Gate to Source Breakdown Voltage	V <sub>DS</sub> = 0V, I <sub>G</sub> = -1μA	-25			V
I <sub>GSS</sub>	Gate to Source Reverse Current	$V_{GS} = -15V$ , $V_{DS} = 0V$ , $T_A = 25$ °C $V_{GS} = -15V$ , $V_{DS} = 0V$ , $T_A = 125$ °C			-150 -150	pA nA
V <sub>GS(OFF)</sub>	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1nA	-2.5		-6	V
V <sub>GS(F)</sub>	Gate to Source Forward Voltage	V <sub>DS</sub> = 0V, I <sub>G</sub> = 10mA			1	V
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = 0V$ , $V_{DS} = 10V$ (Pulsed)	24		60	mA

**Dynamic Characteristics** (@ TA = 25°C, Unless otherwise specified)

			U310			
	Parameters	Conditions	Min	Тур	Max	Unit
	Forward	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 1kHz	10	17		
GFS	Transconductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz		15		mS
	ransconductance	$V_{DS} = 10V$ , $I_D = 10mA$ , $f = 450MHz$		14		
		$V_{DS} = 10V$ , $I_{D} = 10$ mA, $f = 1$ kHz			250	
Gos	Output Conductance	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz		0.18		μS
		V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 450MHz		0.32		
GPS	Power Gain	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz	14	16		dB
GPS	Power Gain	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 450MHz	10	11		иь
۲.	Drain Gate	V <sub>DS</sub> = 10V, V <sub>GS</sub> = -10V, f = 1MHz			2.5	pF
$C_{dg}$	Capacitance	VBS - 10V, VGS10V, I - 11VIIIZ			2.5	ρг
Cgs	Source Gate	V <sub>DS</sub> = 10V, V <sub>GS</sub> = -10V, f = 1MHz			5	рF
Cgs	Capacitance	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 10V, 1 = 11V1112			,	ρı
e <sub>n</sub>	Noise Voltage	$V_{DS} = 10V$ , $I_{D} = 10mA$ , $f = 100kHz$		10		nV/√Hz
NE	Noise Figure	V <sub>DS</sub> = 10V, I <sub>D</sub> = 10mA, f = 105MHz	·	1.5	2	dB
NF	Noise Figure	$V_{DS} = 10V$ , $I_D = 10$ mA, $f = 450$ MHz		2.7	3.5	ив



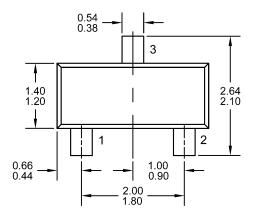


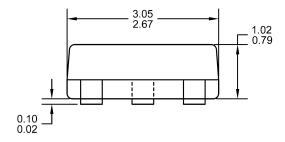


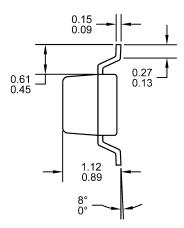


# SOT23 (TO-236AB) Mechanical and Layout Data

## **Package Outline Data**

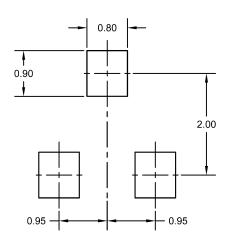






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

#### **Suggested Pad Layout**



- L. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



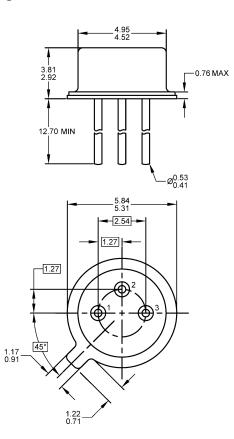






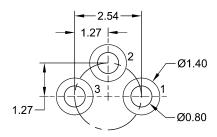
# **TO-52 Mechanical and Layout Data**

# **Package Outline Data**



- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.26 grams
- 3. Bulk product is shipped in standard ESD shipping material
- 4. Refer to JEDEC standards for additional information.

# **Suggested Through-Hole Layout**



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.



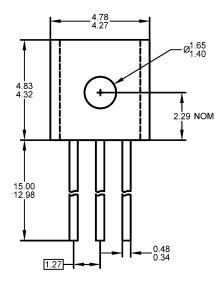


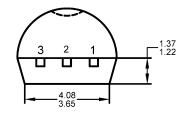


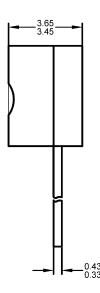


# **TO-92 Mechanical and Layout Data**

## **Package Outline Data**

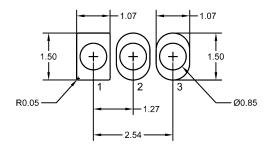






- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

## **Suggested Through-Hole Layout**



- 1. All linear dimensions are in millimeters.
- The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for JFET category:

Click to view products by InterFET manufacturer:

Other Similar products are found below:

MCH3914-8-TL-H F5606 2SK2394-6-TB-E CPH5901G-TL-E MCH3914-7-TL-H MCH5908H-TL-E CPH5902G-TL-E CPH5905G-TL-E CPH5905H-TL-E 2SK2394-7-TB-E NSVJ2394SA3T1G 2N3819 PN4393 MMBFJ176 2N4393 U311 2N5397 2SK208-GR(TE85L,F) MMBF4393LT1G J176\_D74Z IF4500 SMP4338 SMP147 SMP4117 SMP5116 SMPJ232 SMPJ310 SMPJ109 SMP4856 IF1330 SMPJ201 SMP4340 SMP5484 IFN5566 2N2609 2N3821 2N3823 2N3970 2N3971 2N3972 2N4091 2N4092 2N4093 2N4118 2N4118A 2N4220 2N4221 2N4221A 2N4338 2N4339